



## KHX2250C9D3T1K2/4GX

### 4GB (2GB 256M x 64-Bit x 2 pcs.) DDR3-2250MHz

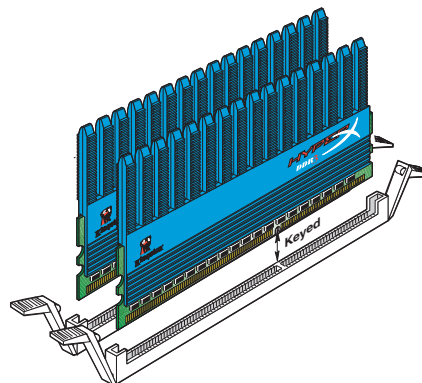
### CL9 240-Pin DIMM Kit

#### DESCRIPTION:

Kingston's KHX2250C9D3T1K2/4GX is a kit of two 256M x 64-bit (2GB) DDR3-2250MHz CL9 SDRAM (Synchronous DRAM) memory modules, based on sixteen 128M x 8-bit DDR3 FBGA components per module. Each module kit supports **Intel® XMP** (Extreme Memory Profiles). Total kit capacity is 4GB. Each module has been tested to run at DDR3-2250MHz at a low latency timing of 9-11-9 at 1.65V. The SPDs are programmed to JEDEC standard latency DDR3-1333MHz timing of 9-9-9 at 1.5V. Each 240-pin DIMM uses gold contact fingers and requires +1.5V. The JEDEC standard electrical and mechanical specifications are as follows:

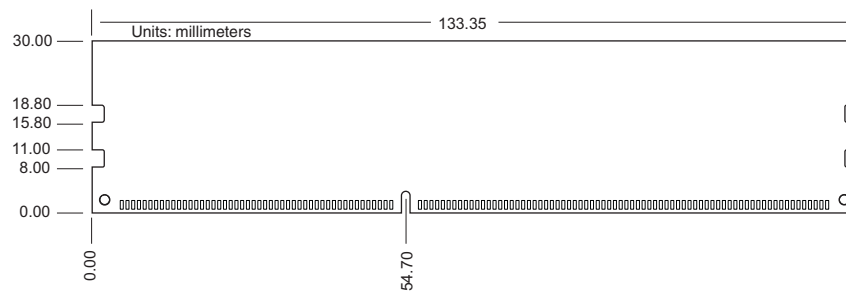
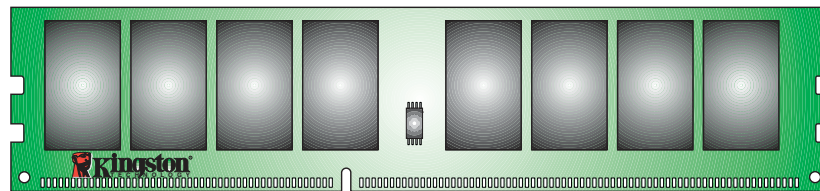
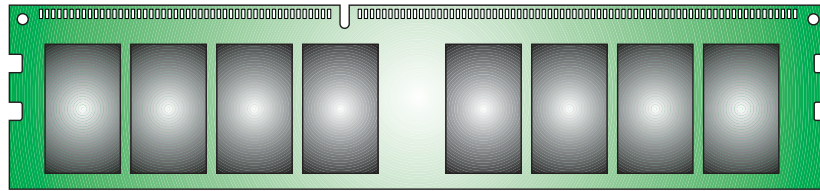
#### FEATURES:

- ✓ JEDEC standard 1.5V  $\pm$  0.075V Power Supply
- ✓ VDDQ = 1.5V  $\pm$  0.075V
- ✓ 667MHz fCK for 1333Mb/sec/pin
- ✓ 8 independent internal bank
- ✓ Programmable CAS Latency: 6,7,8,9
- ✓ Posted CAS
- ✓ Programmable Additive Latency: 0, CL - 2, or CL - 1 clock
- ✓ Programmable CAS Write Latency(CWL) = 7(DDR3-1333)
- ✓ 8-bit pre-fetch
- ✓ Burst Length: 8 (Interleave without any limit, sequential with starting address "000" only), 4 with tCCD = 4 which does not allow seamless read or write [either on the fly using A12 or MRS]
- ✓ Bi-directional Differential Data Strobe
- ✓ Internal(self) calibration : Internal self calibration through ZQ pin (RZQ : 240 ohm  $\pm$  1%)
- ✓ On Die Termination using ODT pin
- ✓ Average Refresh Period 7.8us at lower then TCASE 85°C, 3.9us at 85°C < TCASE . 95°C
- ✓ Asynchronous Reset
- ✓ PCB : Height 2.401" (61.00mm) w/ heatsink, double sided component



#### PERFORMANCE:

- |  |                                |
|--|--------------------------------|
| ✓ CL(IDD)  | 9 cycles                       |
| ✓ Row Cycle Time (tRCmin)                          | 49.5ns (min.)                  |
| ✓ Refresh to Active/Refresh Command Time (tRFCmin) | 110ns                          |
| ✓ Row Active Time (tRASmin)                        | 36ns (min.)                    |
| ✓ Power  | 1.800 W (operating per module) |
| ✓ UL Rating  | 94 V - 0                       |
| ✓ Operating Temperature                            | 0° C to 85° C                  |
| ✓ Storage Temperature                              | -55° C to +100° C              |

**MODULE DIMENSIONS:**

**w/ heatsink assembly**

